

Description

The TCS1616N01 uses advanced trench technology to provide excellent $R_{DS(ON)}$ and low gate charge. It can be used in a wide variety of applications.

General Features

• V_{DS} =60V, I_D =160A

 $R_{DS(ON)} < 3.5m\Omega$ @ V_{GS}=10V

- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Application

- Motor control and drive
- Battery management
- Uninterruptible Power Supply



Absolute Maximum Ratings (TC=25°C unless otherwise noted)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	60	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	ID	160	А
Drain Current-Continuous (TC=100°C)	ID	115	А
Pulsed Drain Current (Note 1)	I _{DM}	640	А
Maximum Power Dissipation	P _D	254	W
Avalanche Energy (L=0.5mH)	E _{AS}	353	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 175	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{ extsf{ heta}JC}$	0.59	°C/W
--	-----------------------	------	------